

GBJ10005 - GBJ1010

10A GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- High Case Dielectric Strength of 1500V_{RMS}
- Low Reverse Leakage Current
- Surge Overload Rating to 170A Peak
- Ideal for Printed Circuit Board Applications
- Plastic Material UL Flammability Classification 94V-0
- UL Listed Under Recognized Component Index

Mechanical Data

• Case: Molded Plastic

 Terminals: Plated Leads, Solderable per MIL-STD-202, Method 208

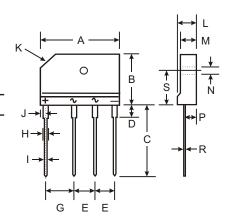
• Polarity: Molded on Body

Mounting: Through Hole for #6 Screw

• Mounting Torque: 5.0 in-lbs Maximum

• Weight: 6.6 grams (approx.)

Marking: Type Number



GBJ								
Dim	Min	Max						
Α	29.70	30.30						
В	19.70	20.30						
С	17.00	18.00						
D	3.80	4.20						
E	7.30	7.70						
G	9.80	10.20						
Н	2.00	2.40						
I	0.90	1.10						
J	2.30	2.70						
K	3.0 X 45°							
L	4.40	4.80						
M	3.40	3.80						
N	3.10	3.40						
Р	2.50	2.90						
R	0.60	0.80						
S	10.80	11.20						
All Dimensions in mm								

Maximum Ratings and Electrical Characteristics @ TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	GBJ 10005	GBJ 1001	GBJ 1002	GBJ 1004	GBJ 1006	GBJ 1008	GBJ 1010	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		50	100	200	400	600	800	1000	V
RMS Reverse Voltage		35	70	140	280	420	560	700	V
Average Forward Rectified Output Current @ T _C = 110°C		10							А
Non-Repetitive Peak Forward Surge Current, 8.3 ms single half-sine-wave superimposed on rated load (JEDEC method)		170						А	
Forward Voltage per element @ I _F = 5.0A		1.05							V
$ \begin{array}{llllllllllllllllllllllllllllllllllll$		10 500							μА
I ² t Rating for Fusing (t < 8.3ms) (Note 1)		120							A ² s
Typical Junction Capacitance per Element (Note 2)		55							pF
Typical Thermal Resistance, Junction to Case (Note 3)		1.4						°C/W	
Operating and Storage Temperature Range		-65 to +150						°C	

Notes:

- 1. Non-repetitive, for t > 1.0ms and < 8.3ms.
- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.
- 3. Thermal resistance from junction to case per element. Unit mounted on 150 x 150 x 1.6mm copper plate heat sink.

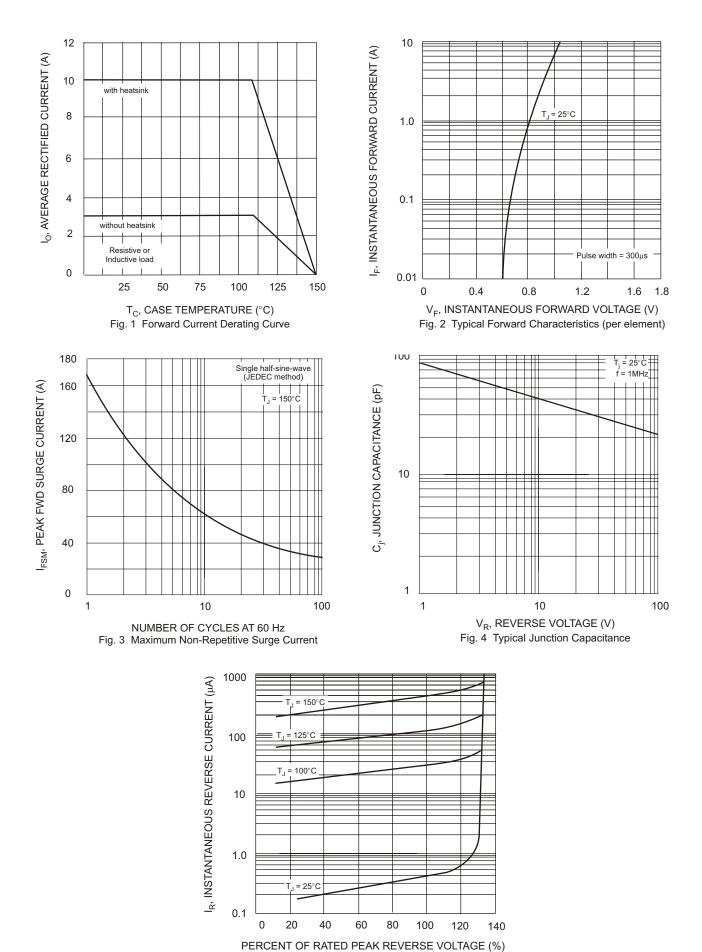


Fig. 5 Typical Reverse Characteristics